Kindly enter the following amendments:

## IN THE CLAIMS:

Please amend Claims 1 - 2, 5 - 8 and 11 - 14 as follows:

1. (Once Amended) A delay circuit for delaying a logic signal having two logic levels consisting of a low level and a high level, comprising:

an inverter chain containing not less than one inverter; and

a metal-oxide-semiconductor capacitor, known as a MOS capacitor, <u>having a single transistor per stage of the inverter chain</u> connected to an output section of the inverter and, when a logic signal having a targeted logic level is input, changes from an off-state to an on-state during a transition period of a signal that appears in the output section of the inverter, wherein each stage is tied alternately to one of a power voltage source and a ground voltage source.

2. (Once Amended) A delay circuit for delaying a logic signal having two logic levels consisting of a low level and a high level, comprises:

an inverter chain containing not less than one inverter; and

a metal-oxide-semiconductor capacitor, known as a MOS capacitor, <u>having a single transistor per stage of the inverter chain</u> connected to an output section of the inverter and exhibiting changes in its capacitance to correspond with changes in output resistance of the inverter in relation to a source voltage, <u>wherein each stage is tied alternately to one of a power voltage source and a ground voltage source</u>.

- 5. (Once Amended) A delay circuit according to claim 1, wherein the MOS capacitor is a node disposed on a transmission path of a logic signal, and is <u>at least</u> represented by [an] <u>a single</u> n-MOS transistor whose gate is connected to a <u>first</u> node <u>of the inverter chain</u> that changes a logic level of the logic signal from a low level to a high level, and whose source and whose drain are fixed at a ground potential.
- 6. (Once Amended) A delay circuit according to claim 1, wherein the MOS capacitor is a node disposed on a transmission path of a logic signal, and is <u>at least</u> represented by a <u>single p-MOS</u> transistor whose gate is connected to a <u>first node of the inverter chain</u> that changes a logic level of the logic signal from a high level to a low level, and whose source and drain are fixed at a [ground] <u>power potential</u>.
- 7. (Once Amended) A delay circuit [according to claim 1] for delaying a logic signal having two logic levels consisting of a low level and a high level, comprising:

an inverter chain containing not less than one inverter; and

a metal-oxide-semiconductor capacitor, known as a MOS capacitor, connected to an output section of the inverter and, when a logic signal having a targeted logic level is input, changes from an off-state to an on-state during a transition period of a signal that appears in the output section of the inverter,

wherein the MOS capacitor is a node disposed on a transmission path of a logic signal, and is represented by an n-MOS transistor whose source and drain are connected to a node that changes a logic level of the logic signal from a high level to a low level, and whose gate is fixed at a source voltage.

8. (Once Amended) A delay circuit [according to claim 1] for delaying a logic signal having two logic levels consisting of a low level and a high level, comprising:

an inverter chain containing not less than one inverter; and

a metal-oxide-semiconductor capacitor, known as a MOS capacitor, connected to an output section of the inverter and, when a logic signal having a targeted logic level is input, changes from an off-state to an on-state during a transition period of a signal that appears in the output section of the inverter,

wherein the MOS capacitor is a node disposed on a transmission path of a logic signal, and is represented by a p-MOS transistor whose source and drain are connected to a node that changes a logic level of a logic signal from a high level to a low level, and whose gate is fixed at a ground potential.

11. (Once Amended) A delay circuit according to claim 2, wherein the MOS capacitor is a node disposed on a transmission path of a logic signal, and is at least represented by [an] a single n-MOS transistor whose gate is connected to a first node of the inverter chain that changes a logic level of the logic signal from a low level to a high level, and whose source and whose drain are fixed at a ground potential.

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- 12. (Once Amended) A delay circuit according to claim 2, wherein the MOS capacitor is a node disposed on a transmission path of a logic signal, and is at least represented by a single p-MOS transistor whose gate is connected to a first node of the inverter chain that changes a logic level of the logic signal from a high level to a low level, and whose source and drain are fixed at a ground potential.
- 13. (Once Amended) A delay circuit [according to claim 2] for delaying a logic signal having two logic levels consisting of a low level and a high level, comprises:

an inverter chain containing not less than one inverter; and

a metal-oxide-semiconductor capacitor, known as a MOS capacitor, connected to an output section of the inverter and exhibiting changes in its capacitance to correspond with changes in output resistance of the inverter in relation to a source voltage,

wherein the MOS capacitor is a node disposed on a transmission path of a logic signal, and is represented by an n-MOS transistor whose source and drain are connected to a node that changes a logic level of the logic signal from a high level to a low level, and whose gate is fixed at a source voltage.